

Bipolar PNP Bare Die – BTP6974

Part Description

The BTP6974 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications. NPN complement is BTN6974

Key Parameters:

- VCBO = -120V
- VCEO = -100V
- VEBO = -5V
- hFE = 100-300 @ VCE = -2V, IC = -0.5A
- VCE(Sat) = -0.5V @ IC = -1A, IB = -100mA
- · fT = 100 MHz @ VCE = -5V, IE = 0A
- COBO = 30pF @ VCB = -10V

Features

Very Low VCE(sat)

Die Size (Unsawn)

1010µm X 1010µm, 40 Mils X 40 Mils

This is a shortform datasheet only For the full datasheet

Please contact sales@siliconsupplies.com

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